

2SK1515, 2SK1516

Silicon N Channel MOS FET

REJ03G0946-0200 (Previous: ADE-208-1286) Rev.2.00 Sep 07, 2005

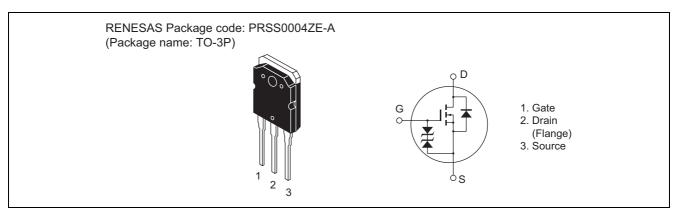
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- Built-in fast recovery diode ($t_{rr} = 120 \text{ ns}$)
- Suitable for motor control, switching regulator, DC-DC converter

Outline





Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1515	V _{DSS}	450	V
	2SK1516		500	
Gate to source voltage		V _{GSS}	±30	V
Drain current		ID	10	А
Drain peak current		I _{D(pulse)} * ¹	30	А
Body to drain diode reverse drain current		I _{DR}	10	А
Channel dissipation		Pch* ²	100	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C
Channel temperature		Tch	150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at $T_C = 25^{\circ}C$

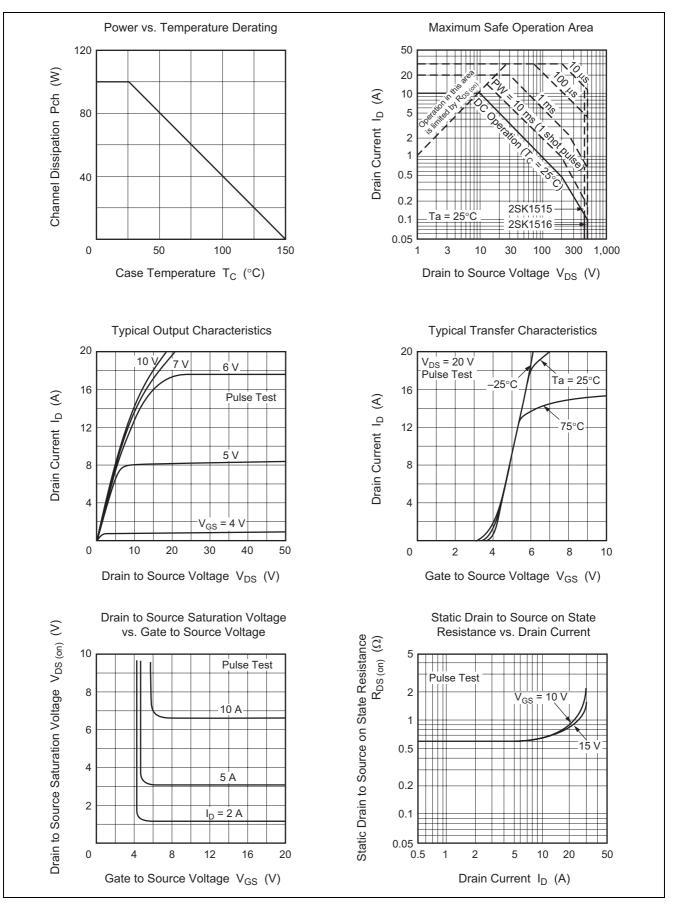
Electrical Characteristics

							$(Ta = 25^{\circ}C)$
ltem		Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source	2SK1515	V _{(BR)DSS}	450	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
breakdown voltage	2SK1516		500				
Gate to source breakdown voltage		V _{(BR)GSS}	±30	—	—	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current		I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, \text{ V}_{DS} = 0$
Zero gate voltage drain	2SK1515	I _{DSS}	—	—	250	μA	$V_{DS} = 360 \text{ V}, \text{ V}_{GS} = 0$
	2SK1516						$V_{DS} = 400 V, V_{GS} = 0$
Gate to source cutoff voltage		V _{GS(off)}	2.0	_	3.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on	2SK1515	R _{DS(on)}	_	0.6	0.8	Ω	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$
state resistance	2SK1516		_	0.7	0.9		
Forward transfer admittance		y _{fs}	4.0	7.0	_	S	$I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$
Input capacitance		Ciss	_	1100	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance		Coss		310	_	pF	f = 1 MHz
Reverse transfer capacitance		Crss	_	50	—	pF	
Turn-on delay time		t _{d(on)}	_	15	—	ns	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V},$
Rise time		tr	_	65		ns	$R_L = 6 \Omega$
Turn-off delay time		t _{d(off)}	_	95		ns	
Fall time		t _f	_	55		ns	
Body to drain diode forward voltage		V _{DF}	_	1.0	—	V	$I_F = 10 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time		t _{rr}	—	120	—	ns	$I_F = 10 \text{ A}, V_{GS} = 0,$ $di_F/dt = 100 \text{ A}/\mu \text{s}$

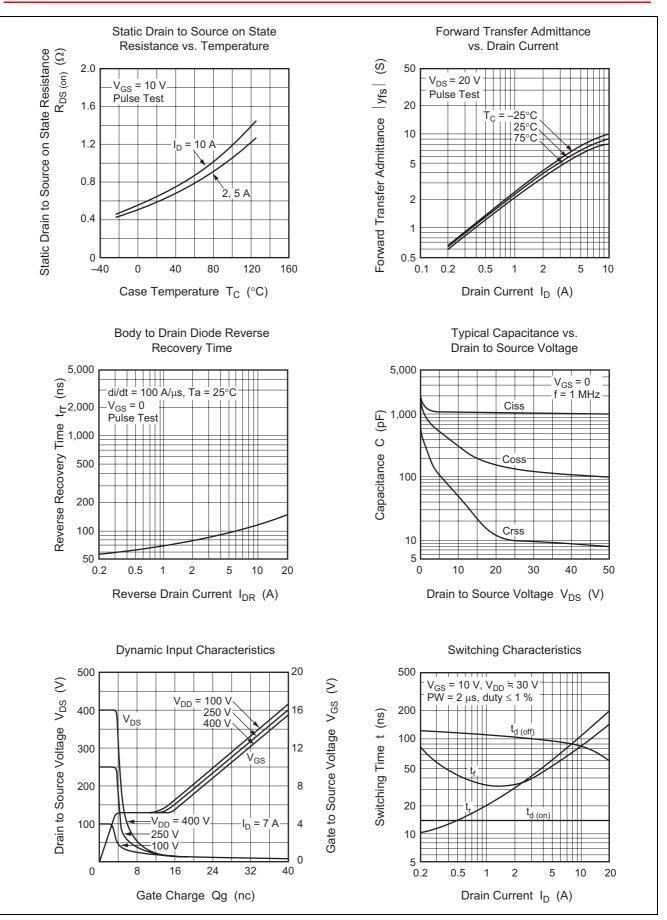
Note: 3. Pulse test



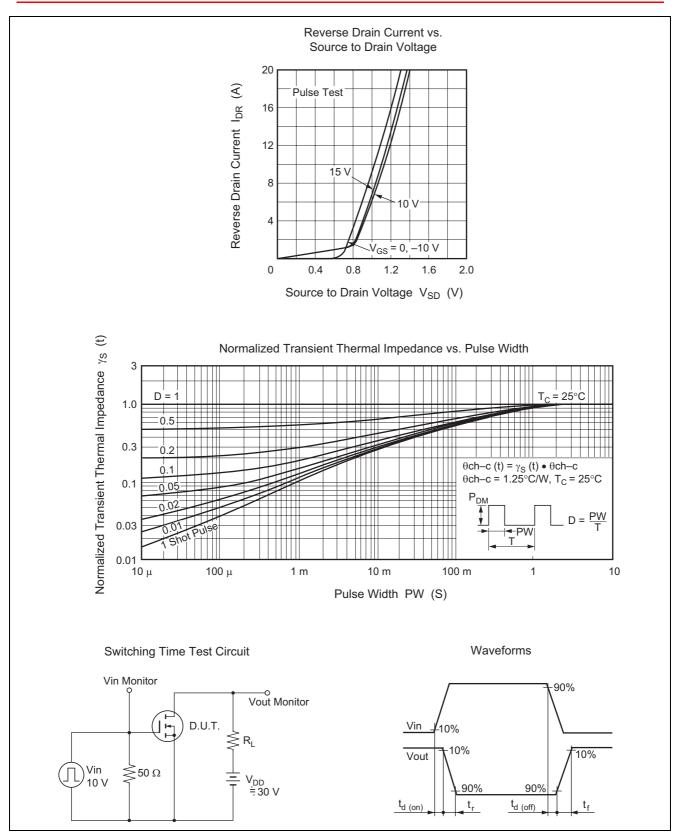
Main Characteristics



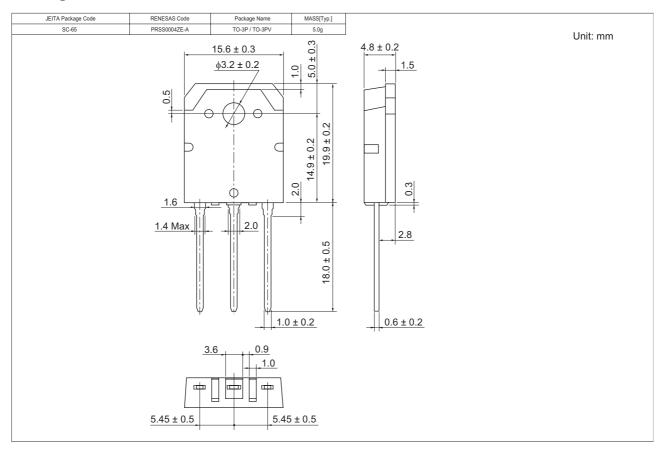








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK1515-E	360 pcs	Box (Tube)
2SK1516-E	360 pcs	Box (Tube)

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs! 1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

Notes regarding these materials

- Notes regarding these materials
 These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party.
 Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
 All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corp. vithout notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor for the latest product information before purchasing a product listed herein.
 The information described here may contain technical inaccuracies or typographical errors. Renesas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors. Please also pay attention to information published by Renesas Technology Corp. by various means, including the Renesas Technology Corp. Semiconductor home page (http://www.renesas.com).
 When using any or all of the information contained in these materials. including product data, diagrams, charts, programs, and algorithms, please be sure to

- Nome page (ntp://www.renesas.com).
 4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corp. assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.
 5. Renesas Technology Corp. semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- use. 6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials. 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited. 8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



RENESAS SALES OFFICES

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology Hong Kong Ltd.

7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. Unit2607 Ruijing Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

© 2005. Renesas Technology Corp., All rights reserved. Printed in Japan. Colophon .3.0

http://www.renesas.com